

# AC/DC to Logic Interface Optocouplers

# Technical Data

### HCPL-3700 HCPL-3760

#### Features

- Standard (HCPL-3700) and Low Input Current (HCPL-3760) Versions
- AC or DC Input
- Programmable Sense Voltage
- Hysteresis
- Logic Compatible Output
- Thresholds Guaranteed over Temperature
- Thresholds Independent of LED Optical Parameters
- Recognized under UL 1577 and CSA Approved for Dielectric Withstand Proof Test Voltage of 2500 Vac, 1 Minute

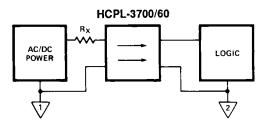
### Applications

- Limit Switch Sensing
- Low Voltage Detector
- 5 V-240 V AC/DC Voltage Sensing
- Relay Contact Monitor
- Relay Coil Voltage Monitor
- Current Sensing
- Microprocessor Interfacing

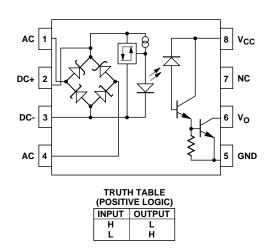
## Description

The HCPL-3700 and HCPL-3760 are voltage/current threshold detection optocouplers. The HCPL-3760 is a low-current version of the HCPL-3700. To obtain lower current operation, the HCPL-3760 uses a highefficiency AlGaAs LED which provides higher light output at lower drive currents. Both devices utilize threshold sensing input buffer ICs which permit control of threshold levels over a wide range of input voltages with a single external resistor.

# **Functional Diagram**



The input buffer incorporates several features: hysteresis for extra noise immunity and switching immunity, a diode bridge for easy use with ac input signals, and internal clamping



CAUTION: It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.

diodes to protect the buffer and LED from a wide range of overvoltage and over-current transients. Because threshold sensing is done prior to driving the LED, variations in optical coupling from the LED to the detector will have no effect on the threshold levels.

The HCPL-3700's input buffer IC has a nominal turn on threshold of 2.5 mA ( $I_{TH}$  +) and 3.7 volts ( $V_{TH}$  +).

The buffer IC for the HCPL-3760 was redesigned to permit a lower input current. The nominal turn on threshold for the HCPL-3760 is 1.2 mA ( $I_{TH}$  +) and 3.7 volts ( $V_{TH}$  +).

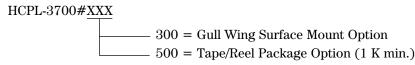
The high gain output stage features an open collector output providing both TTL compatible saturation voltages and CMOS compatible breakdown voltages.

By combining several unique functions in a single package, the user is provided with an ideal component for industrial control computer input boards and other applications where a predetermined input threshold level is desirable.

#### **Ordering Information**

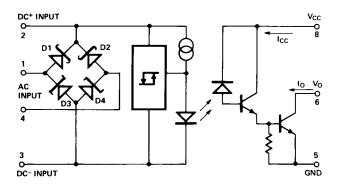
Specify Part Number followed by Option Number (if desired)

Example



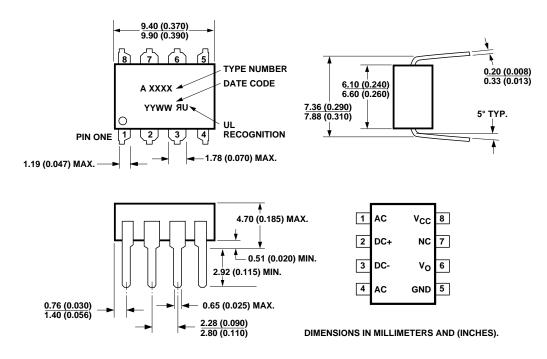
Option data sheets available. Contact your Agilent sales representative or authorized distributor for information.

Schematic

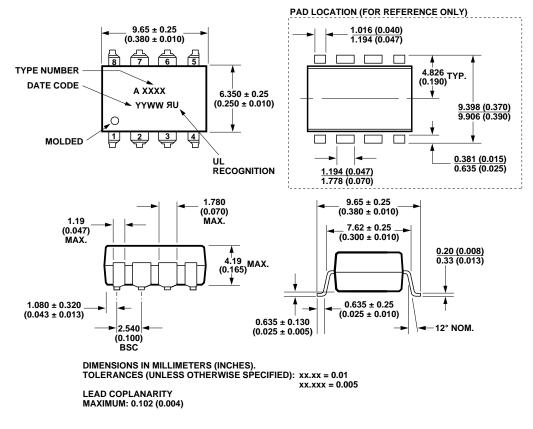


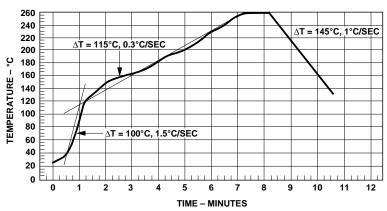
# Package Outline Drawings

**Standard DIP Package** 



**Gull Wing Surface Mount Option 300** 





### **Maximum Solder Reflow Thermal Profile**

(NOTE: USE OF NON-CHLORINE ACTIVATED FLUXES IS RECOMMENDED.)

## **Regulatory Information**

The HCPL-3700/60 has been approved by the following organizations:

#### UL

Recognized under UL 1577, component recognition program, File E55361.

#### CSA

Approved under CSA Component Acceptance Notice #5, File CA 88324.

Parameter	Symbol	Value	Units	Conditions
Min. External Air Gap (External Clearance)	L(IO1)	7.1	mm	Measured from input terminals to output terminals, shortest distance through air
Min. External Tracking Path (External Creepage)	L(IO2)	7.4	mm	Measured from input terminals to output terminals, shortest distance path along body
Min. Internal Plastic Gap (Internal Clearance)		0.08	mm	Through insulation distance, conductor to conductor, usually the direct distance between the photoemitter and photodetector inside the optocoupler cavity
Tracking Resistance (Comparative Tracking Index)	CTI	200	V	DIN IEC 112/VDE 0303 PART 1
Isolation Group		IIIa		Material Group (DIN VDE 0110, 1/89, Table 1)

**Insulation and Safety Related Specifications** 

Option 300 – surface mount classification is Class A in accordance with CECC 00802.

# Absolute Maximum Ratings (No derating required up to 70°C)

Paramet	er	Symbol	Min.	Max.	Units	Note
Storage Temperature	T <sub>S</sub>	-55	125	°C		
Operating Temperature	T <sub>A</sub>	-40	85	°C		
Lead Soldering Cycle	Temperature			260	°C	1
	Time			10	s	
Input Current	Average			50		2
	Surge	I <sub>IN</sub>		140	mA	2, 3
	Transient			500	-	
Input Voltage (Pins 2-3)	Input Voltage (Pins 2-3)				V	
Input Power Dissipation		P <sub>IN</sub>		230	mW	4
Total Package Power Dis	sipation	P <sub>T</sub>		305	mW	5
Output Power Dissipation	n	Po		210	mW	6
Output Current Average		I <sub>O</sub>		30	mA	7
Supply Voltage (Pins 8-5)		V <sub>CC</sub>	-0.5	20	V	
Output Voltage (Pins 6-5	Vo	-0.5	20	V		
Solder Reflow Temperatu	ıre Profile	Se	e Package	Outline Dra	awings section	on

# **Recommended Operating Conditions**

Parameter	Symbol	Min.	Max.	Units	Note
Supply Voltage	V <sub>CC</sub>	2	18	V	
Operating Temperature	T <sub>A</sub>	0	70	°C	
Operating Frequency	f	0	4	kHz	8

Electrical Specifications Over Recommended Temperature  $T_A = 0$ °C to 70°C, Unless Otherwise Specified.

Pa	rameter	Sym.	Device	Min.	Typ. <sup>[9]</sup>	Max.	Units	Conditions	Fig.	Note
Input Thre	shold	$I_{\rm TH+}$	HCPL-3700	1.96	2.5	3.11	mA	$V_{IN} = V_{TH+}; V_{CC} = 4.5 V;$	2, 3	14
Current			HCPL-3760	0.87	1.2	1.56		$V_0 = 0.4 \text{ V}; I_0 \ge 4.2 \text{ mA}$		
		$I_{TH-}$	HCPL-3700	1.00	1.3	1.62		$V_{IN} = V_{TH}$ ; $V_{CC} = 4.5 V$ ;		
			HCPL-3760	0.43	0.6	0.80		$V_{O} = 2.4 \text{ V}; I_{OH} \le 100 \mu\text{A}$		
Voltage	DC (Pins 2, 3)	V <sub>TH+</sub>		3.35	3.7	4.05	V	$\begin{array}{l} V_{IN} = V_2 \mbox{-} V_3; \mbox{Pins 1 & 4 Open} \\ V_{CC} = 4.5 \mbox{ V}; \mbox{V}_O = 0.4 \mbox{ V}; \\ I_O \geq \mbox{ 4.2 mA} \end{array}$		
		V <sub>TH-</sub>		2.01	2.6	2.86	V	$\begin{array}{l} V_{IN} = V_2 - V_3;  Pins \; 1 \; \& \; 4 \; Open \\ V_{CC} = \; 4.5 \; V;  V_O = \; 2.4 \; V; \\ I_O \leq \; 100 \; \mu A \end{array}$		
	AC (Pins 1, 4)	V <sub>TH+</sub>		4.23	4.9	5.50	V	$ \begin{array}{l} V_{IN} = \;  V_1 - V_4   ; \\ Pins \; 2 \; \& \; 3 \; Open \\ V_{CC} = \; 4.5 \; V; \; V_O = \; 0.4 \; V; \\ I_O \geq \; 4.2 \; mA \end{array} $		14, 15
		V <sub>TH-</sub>		2.87	3.7	4.20	V	$\begin{split} V_{IN} &=  V_1 - V_4 ; \\ Pins \ 2 \ \& \ 3 \ Open \\ V_{CC} &= 4.5 \ V; \ V_O = 2.4 \ V; \\ I_O &\leq \ 100 \ \mu A \end{split}$		
Hysteresis		I <sub>HYS</sub>	HCPL-3700		1.2		mA	$I_{\rm HYS} = I_{\rm TH+} - I_{\rm TH-}$	2	
			HCPL-3760		0.6					
		V <sub>HYS</sub>			1.2		V	$V_{\rm HYS} = V_{\rm TH+} - V_{\rm TH-}$	1	
Input Clamp Voltage		V <sub>IHC1</sub>		5.4	6.0	6.6	V	$\begin{split} V_{IHC1} &= V_2 - V_3; V_3 = GND; \\ I_{IN} &= 10 \text{ mA}; \text{ Pins } 1 \& 4 \\ \text{Connected to Pin } 3 \end{split}$	1	
		V <sub>IHC2</sub>		6.1	6.7	7.3	V	$V_{IHC2} =  V_1 - V_4 ;$ $ I_{IN}  = 10 \text{ mA};$ Pins 2 & 3 Open		
		V <sub>IHC3</sub>			12.0	13.4	V			
		V <sub>ILC</sub>			-0.76		V			
Input Curre	ent	$I_{IN}$	HCPL-3700	3.0	3.7	4.4	mA	$V_{IN} = V_2 - V_3 = 5.0 V$	5	
			HCPL-3760	1.5	1.8	2.2		Pins 1 & 4 Open		
Bridge Dio		V <sub>D1,2</sub>	HCPL-3700		0.59		V	$I_{IN} = 3 \text{ mA}$		
Forward V	oltage		HCPL-3760		0.51			$I_{IN} = 1.5 \text{ mA}$		
		$V_{D3,4}$	HCPL-3700		0.74			$I_{IN} = 3 \text{ mA}$		
			HCPL-3760		0.71			$I_{IN} = 1.5 \text{ mA}$		
Logic Low Voltage	Logic Low Output V <sub>OL</sub>				0.1	0.4	V	$V_{CC} = 4.5 \text{ V}; I_{OL} = 4.2 \text{ mA}$	5	14
Logic High Output Cu		I <sub>OH</sub>				100	μA	$V_{OH} = V_{CC} = 18 \text{ V}$		14
Logic Low	Supply	I <sub>CCL</sub>	HCPL-3700		1.2	4	mA	$V_2 - V_3 = 5.0 V; V_0 = Open;$	6	
Current			HCPL-3760		0.7	3		$V_{\rm CC} = 5.0 \text{ V}$		
Logic High Current	Supply	I <sub>CCH</sub>			0.002	4	μA	$V_{CC} = 18 \text{ V}; V_O = \text{Open}$	4	14
Input Capa	citance	C <sub>IN</sub>			50		pF	$f = 1 MHz; V_{IN} = 0 V,$ Pins 2 & 3, Pins 1 & 4 Open		

Switching Specifications  $T_A = 25^{\circ}C, V_{CC} = 5.0 V$ , Unless Otherwise Specified.

Parameter	Sym.	Device	Min.	Тур.	Max.	Units	Test Conditions	Fig.	Note
Propagation Delay Time to Logic Low	t <sub>PHL</sub>	HCPL-3700		4.0	15.0	μs	$R_{L} = 4.7 \text{ k}\Omega, C_{L} = 30 \text{ pF}$		10
at Output	Th	HCPL-3760		4.5	10.0	μο		7, 10	
Propagation Delay Time to Logic High	t	HCPL-3700		10.0	40.0	μs	$R_{L} = 4.7 \text{ k}\Omega, C_{L} = 30 \text{ pF}$	7,10	11
at Output	t <sub>PLH</sub>	HCPL-3760		8.0	40.0	μs	$n_{\rm L} = 4.7 \text{ Ksz}, 0_{\rm L} = 50 \text{ pr}$		11
Output Rise Time	t <sub>r</sub>	HCPL-3700		20		- μs	$R_L = 4.7 \text{ k}\Omega, C_L = 30 \text{ pF}$		
(10-90%)	ur l	HCPL-3760		14			$n_{\rm L} = 4.7 \text{ Ksz}, 0_{\rm L} = 50 \text{ pr}$	8	
		HCPL-3700		0.3			$P = 4.7 k_0 C = 20 m_z$	0	
Output Fall Time (90-10%)	t <sub>f</sub>	HCPL-3760		0.4		μs	$R_L = 4.7 \text{ k}\Omega, C_L = 30 \text{ pF}$		
Common Mode Transient Immunity at Logic High Output	CM <sub>H</sub>			4000		V/µs	$\begin{split} I_{IN} &= 0 \text{ mA}, R_L = 4.7 \text{ k}\Omega, \\ V_{O \text{ min}} &= 2.0 \text{ V}, V_{CM} = 1400 \text{ V} \end{split}$	0.11	10.10
Common Mode		HCPL-3700		800		<b>X</b> 7/	$I_{IN} = 3.11 \text{ mA}$ $R_L = 4.7 \text{ k}\Omega,$	9,11	12, 13
Transient Immunity at Logic Low Output	CM <sub>L</sub>	HCPL-3760		600		V/ $\mu$ s V <sub>0 max</sub> = V <sub>0 max</sub> = V <sub>0 max</sub> = V <sub>CM</sub> = 14		+	

# **Package Characteristics**

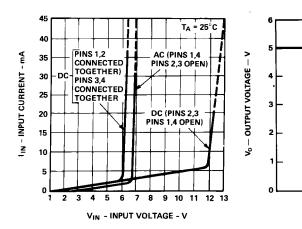
Over Recommended Temperature  $T_A$  = 0  $^\circ\!\mathrm{C}$  to 70  $^\circ\!\mathrm{C},$  Unless Otherwise Specified.

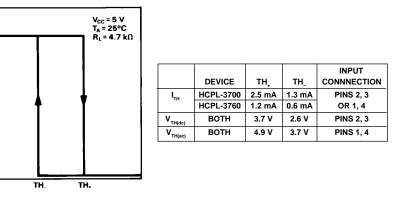
Parameter	Sym.	Min.	Typ. <sup>[9]</sup>	Max.	Units	Conditions	Fig.	Note
Input-Output Momentary Withstand Voltage*	V <sub>ISO</sub>	2500			V rms	$\begin{array}{l} \mathrm{RH} \leq 50\%,  t=1  \min; \\ \mathrm{T}_{\mathrm{A}} = 25^{\circ}\mathrm{C} \end{array}$		$     \begin{array}{c}       16, \\       17     \end{array} $
Input-Output Resistance	R <sub>I-O</sub>		1012		Ω	$V_{I-O} = 500 \text{ Vdc}$		16
Input-Output Capacitance	C <sub>I-O</sub>		0.6		pF	$f = 1 MHz; V_{I-O} = 0 Vdc$		

\*The Input-Output Momentary Withstand Voltage is a dielectric voltage rating that should not be interpreted as an input-output continuous voltage rating. For the continuous voltage rating refer to the VDE 0884 Insulation Characteristics Table (if applicable), your equipment level safety specification, or Agilent Application Note 1074, "Optocoupler Input-Output Endurance Voltage."

#### Notes:

- 1. Measured at a point 1.6 mm below seating plane.
- 2. Current into/out of any single lead.
- 3. Surge input current duration is 3 ms at 120 Hz pulse repetition rate. Transient input current duration is 10 µs at 120 Hz pulse repetition rate. Note that maximum input power, P<sub>IN</sub>, must be observed.
- 4. Derate linearly above 70°C free-air temperature at a rate of 4.1 mW/°C. Maximum input power dissipation of 230 mW allows an input IC junction temperature of  $125^{\circ}$ C at an ambient temperature of  $T_A = 70^{\circ}$ C with a typical thermal resistance from junction to ambient of  $\theta_{JA1} = 240$  °C/W. Excessive  $P_{IN}$  and  $T_J$  may result in IC chip degradation.
- 5. Derate linearly above 70°C free-air temperature at a rate of 5.4 mW/°C.
- 6. Derate linearly above 70°C free-air temperature at a rate of 3.9 mW/°C. Maximum output power dissipation of 210 mW allows an output IC junction temperature of  $125^{\circ}$ C at an ambient temperature of  $T_A = 70^{\circ}$ C with a typical thermal resistance from junction to ambient of  $\theta_{JA0} = 265$ °C/W.
- 7. Derate linearly above 70°C free-air temperature at a rate of 0.6 mA/°C.
- 8. Maximum operating frequency is defined when output waveform Pin 6 obtains only 90% of  $V_{CC}$  with  $R_L = 4.7 \text{ k}\Omega$ ,  $C_L = 30 \text{ pF}$  using a 5 V square wave input signal.
- 9. All typical values are at  $T_A = 25^{\circ}$ C,  $V_{CC} = 5.0$  V unless otherwise stated. 10. The t<sub>PHL</sub> propagation delay is measured from the 2.5 V level of the leading edge of a 5.0 V input pulse (1 µs rise time) to the 1.5 V level on the leading edge of the output pulse (see Figure 10).
- 11. The  $t_{PLH}$  propagation delay is measured from the 2.5 V level of the trailing edge of a 5.0 V input pulse (1 µs fall time) to the 1.5 V level on the trailing edge of the output pulse (see Figure 10).
- 12. Common mode transient immunity in Logic High level is the maximum tolerable (positive)  $dV_{CM}/dt$  on the leading edge of the common mode pulse,  $V_{CM}$ , to insure that the output will remain in a Logic High state (i.e.,  $V_0 > 2.0$  V). Common mode transient immunity in Logic Low level is the maximum tolerable (negative) dV<sub>CM</sub>/dt on the trailing edge of the common mode pulse signal,  $V_{CM}$ , to insure that the output will remain in a Logic Low state (i.e.,  $V_0 < 0.8$  V). See Figure 11.
- 13. In applications where  $dV_{CM}/dt$  may exceed 50,000 V/µs (such as static discharge), a series resistor,  $R_{CC}$ , should be included to protect the detector IC from destructively high surge currents. The recommended value for  $R_{CC}$  is 240  $\Omega$  per volt of allowable drop in  $V_{CC}$  (between Pin 8 and  $V_{CC}$ ) with a minimum value of 240  $\Omega$ .
- 14. Logic low output level at Pin 6 occurs under the conditions of  $V_{IN} \ge V_{TH+}$  as well as the range of  $V_{IN} > V_{TH-}$  once  $V_{IN}$  has exceeded  $V_{TH+}$ . Logic high output level at Pin 6 occurs under the conditions of  $V_{IN} \le V_{TH-}$  as well as the range of  $V_{IN} < V_{TH+}$  once  $V_{IN}$  has decreased below V<sub>TH</sub>.
- 15. AC voltage is instantaneous voltage.
- 16. Device considered a two terminal device: Pins 1, 2, 3, 4 connected together, and Pins 5, 6, 7, 8 connected together.
- 17. In accordance with UL 1577, each optocoupler is proof tested by applying an insulation test voltage  $\geq 3000$  V rms for 1 second (leakage detection current limit,  $I_{i-0} \leq 5 \mu A$ ).





INPUT SIGNAL

Figure 1. Typical Input Characteristics,  $I_{IN}$  vs.  $V_{IN}$  (AC Voltage is Instantaneous Value).

Figure 2. Typical Transfer Characteristics.

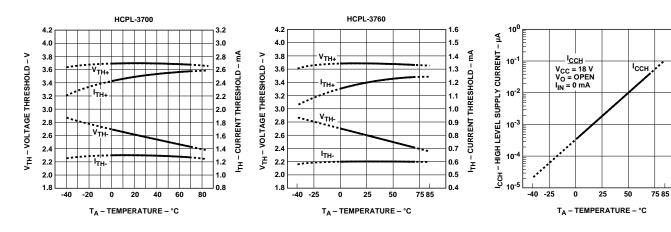


Figure 3. Typical DC Threshold Levels vs. Temperature.

Figure 4. Typical High Level Supply Current,  $\mathbf{I}_{\rm CCH}$  vs. Temperature.

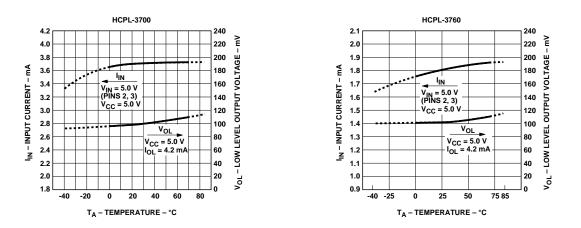


Figure 5. Typical Input Current,  $\mathbf{I}_{_{\rm IN}}$ , and Low Level Output Voltage,  $\mathbf{V}_{_{\rm OL}}$ , vs. Temperature.

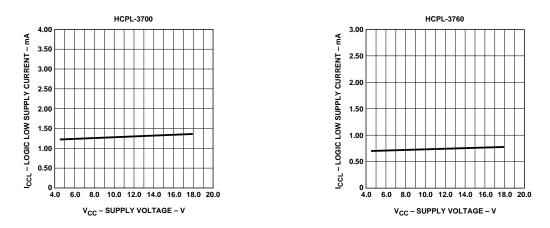


Figure 6. Typical Logic Low Supply Current vs. Supply Voltage.

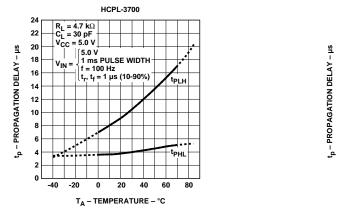


Figure 7. Typical Propagation Delay vs. Temperature.

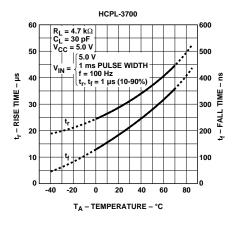


Figure 8. Typical Rise, Fall Times vs. Temperature.

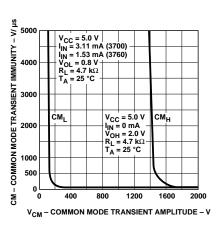
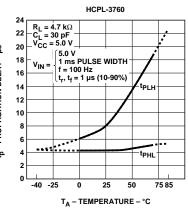
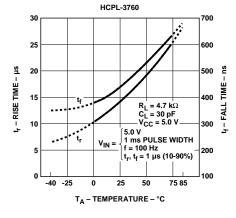


Figure 9. Common Mode Transient Immunity vs. Common Mode Transient Amplitude.





HCPL-3700/60 5V +5V INPUT 2.5V 1 AÇ Vcc 8 VIN oν 0.01µf BYPASS PULSE GENERATOR 7 2 DC+ ξ RL tPLH Z<sub>O</sub> = 50Ω tры 6 3 o vo DC-Vo : CL\* 90% 90% GND 5 4 AC OUTPUT vo VIN 10% 10% CL IS 30 pF, WHICH INCLUDES PROBE AND STRAY WIRING CAPACITANCE. tr Figure 10. Switching Test Circuit.

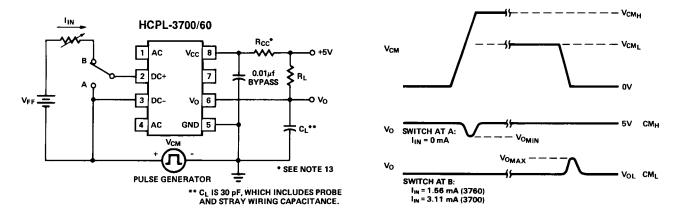


Figure 11. Test Circuit for Common Mode Transient Immunity and Typical Waveforms.

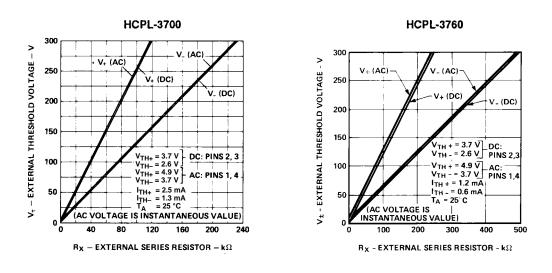


Figure 12. Typical External Threshold Characteristics,  $V \pm$  vs.  $R_x$ .

11

Vон

1.5V

VOL



# Agilent Technologies

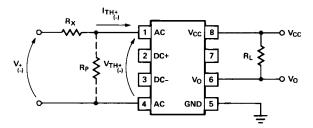


Figure 13. External Threshold Voltage Level Selection.

#### **Electrical Considerations**

The HCPL-3700/3760 optocouplers have internal temperature compensated, predictable voltage and current threshold points which allow selection of an external resistor,  $R_X$ , to determine larger external threshold voltage levels. For a desired external threshold voltage, V<sub>+</sub>, a corresponding typical value of  $R_X$  can be obtained from Figure 12. Specific calculation of  $R_x$  can be obtained from Equation (1). Specification of both V<sub>+</sub> and V<sub>-</sub> voltage threshold levels simultaneously can be obtained by the use of R<sub>X</sub> and R<sub>P</sub> as shown in Figure 13 and determined by Equations (2) and (3).

 $R_X$  can provide over-current transient protection by limiting input current during a transient condition. For monitoring contacts of a relay or switch, the HCPL-3700/3760 in combination with  $R_X$  and  $R_P$  can be used to allow a specific current to be conducted through the contacts for cleaning purposes (wetting current).

The choice of which input voltage clamp level to choose depends upon the application of this device (see Figure 1). It is recommended that the low clamp condition be used when possible. The low clamp condition in conjunction with the low input current feature will ensure extremely low input power dissipation.

In applications where  $dV_{CM}/dt$ may be extremely large (such as static discharge), a series resistor,  $R_{CC}$ , should be connected in series with  $V_{CC}$  and Pin 8 to protect the detector IC from destructively high surge currents. See Note 13 for determination of  $R_{CC}$ . In addition, it is recommended that a ceramic disc bypass capacitor of 0.01 µF be placed between Pins 8 and 5 to reduce the effect of power supply noise.

For interfacing ac signals to TTL systems, output low pass filtering can be performed with a pullup resistor of 1.5 k $\Omega$  and 20  $\mu$ F capacitor. This application requires a Schmitt trigger gate to avoid slow rise time chatter problems. For ac input applications, a filter capacitor can be placed across the dc input terminals for either signal or transient filtering.

Either ac (Pins 1, 4) or dc (Pins 2, 3) input can be used to determine external threshold levels. For one specifically selected external threshold voltage level  $V_+$  or  $V_-$ ,  $R_X$  can be determined without use of  $R_P$  via

$$R_{x} = \frac{V_{+} - V_{TH+}}{I_{TH+}} (-) (1)$$

For two specifically selected external threshold voltage levels,  $V_+$  and  $V_-$ , the use of  $R_X$  and  $R_P$ will permit this selection via equations (2), (3) provided the following conditions are met. If the denominator of equation (2) is positive, then

$$\frac{V_{+}}{V_{-}} \ge \frac{V_{TH+}}{V_{TH-}}$$
 and  $\frac{V_{+} - V_{TH+}}{V_{-} - V_{TH-}} < \frac{I_{TH+}}{I_{TH-}}$ 

Conversely, if the denominator of equation (2) is negative, then

$$\frac{V_{+}}{V_{-}} \leq \frac{V_{TH+}}{V_{TH-}} \text{ and } \frac{V_{+} - V_{TH+}}{V_{-} - V_{TH-}} > \frac{I_{TH+}}{I_{TH+}}$$

$$R_{X} = \frac{V_{TH-} (V_{+}) - V_{TH+} (V_{-})}{I_{TH+} (V_{TH-}) - I_{TH-} (V_{TH+})}$$
(2)

$$R_{P} = \frac{V_{TH-} (V_{+}) - V_{TH+} (V_{-})}{I_{TH+} (V_{-} - V_{TH-}) + I_{TH-} (V_{TH+} - V_{+})} (3)$$

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